

**STANLEY****■ PIN PHOTO DIODE****PP403****■ Absolute Maximum Rating**

Ta = 25°C

Part No.	Power Dissipation Pd	Reverse Voltage VR	Operating Temperature Topr	Storage Temperature Tstg
PP403	75	30	-30~+85	-30~+100
Units	mW	V	°C	°C

**■ Electro-Optical Characteristics**

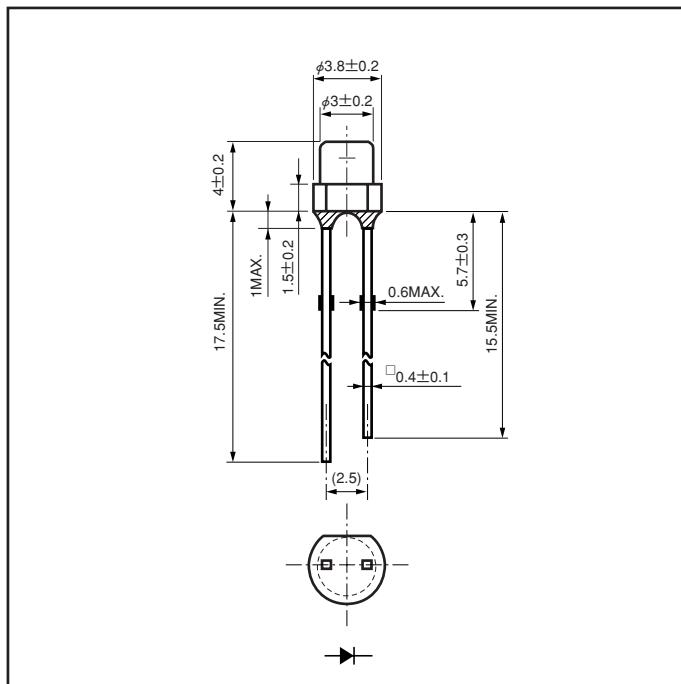
Ta = 25°C

Part No.	Photo Current			Response Time			Capacitance <sup>*1</sup>		Dark Current		Peak Wavelength		Photo Sensitivity	
	Ip		Ee	tr-tf		VR	Ct	VR	ID	VR	λp	VR	TYP	VR
	TYP	VR	Ee	TYP	VR	RL	TYP	VR	MAX	VR	TYP	VR	TYP	VR
PP403	1.5	5	0.5	20	10	1,000	7	10	10	10	950	0	0.64	5
Units	μA	V	mW/cm <sup>2</sup>	ns	V	Ω	pF	V	nA	V	nm	V	A/W	V

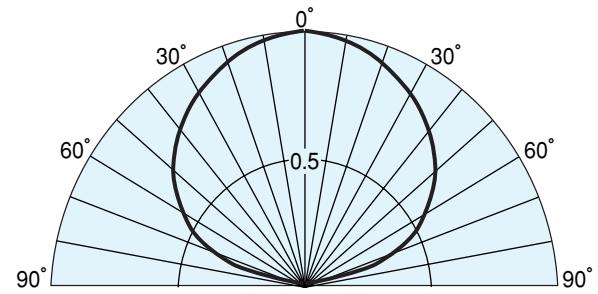
※1 f=1MHz

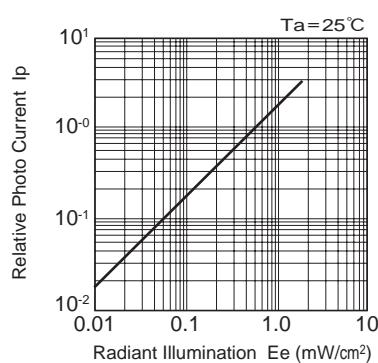
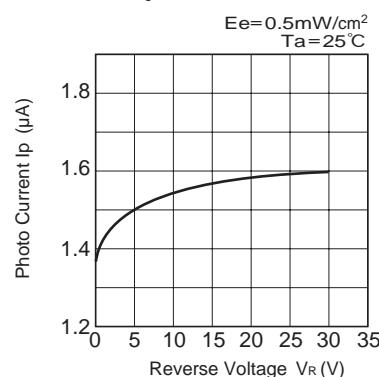
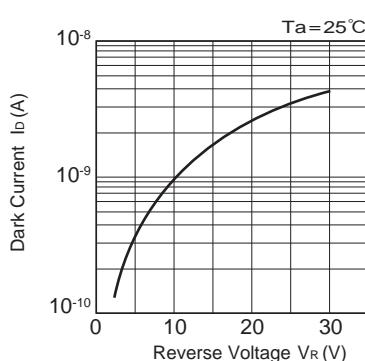
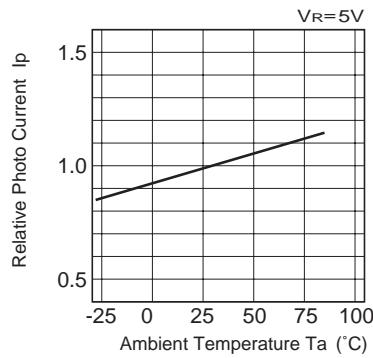
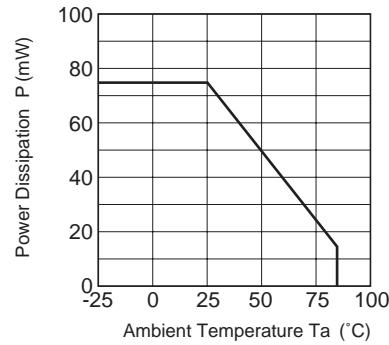
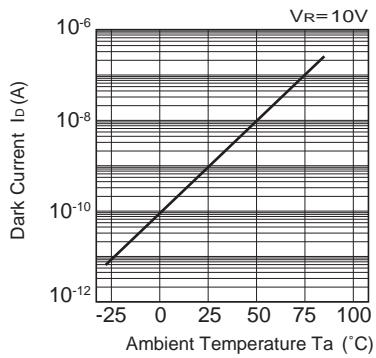
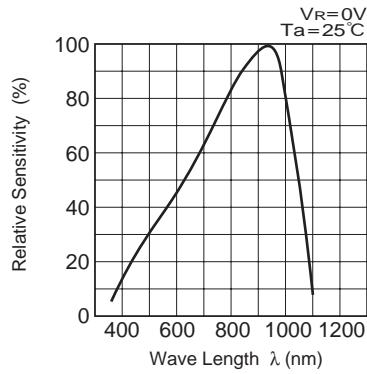
**■ Package Dimensions**

Unit : mm

**■ Spatial Distribution**

Ta = 25°C



**STANLEY****■ PIN PHOTO DIODE****PP403****■ Radiant Illumination vs. Relative Photo Current****■ Reverse Voltage vs. Photo Current****■ Reverse Voltage vs. Dark Current****■ Ambient Temperature vs. Relative Photo Current****■ Ambient Temperature vs. Power Dissipation****■ Ambient Temperature vs. Dark Current****■ Spectral Sensitivity Characteristics****■ Reverse Voltage vs. Terminal Capacitance**